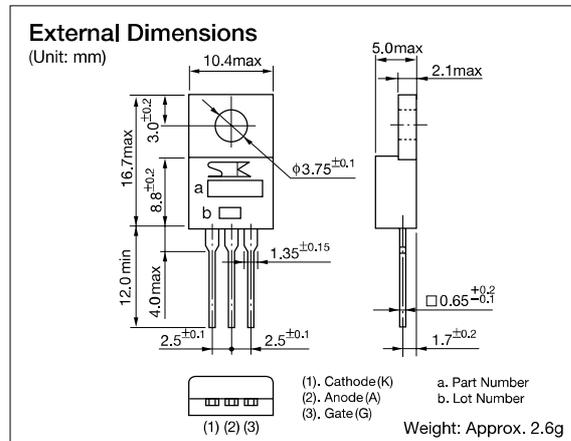


# TO-220 5A Thyristor

## TF521M, TF541M, TF561M

### ■ Features

- Repetitive peak off-state voltage:  $V_{DRM}=200, 400, 600V$
- Average on-state current:  $I_{T(AV)}=5A$
- Gate trigger current:  $I_{GT}=15mA$  max



### ■ Absolute Maximum Ratings

Parameter	Symbol	Ratings			Unit	Conditions
		TF521M	TF541M	TF561M		
Repetitive peak off-state voltage	$V_{DRM}$	200	400	600	V	$T_j = -40$ to $+125^\circ C$ , $R_{GK} = 1k\Omega$
Repetitive peak reverse voltage	$V_{RRM}$	200	400	600	V	
Non-repetitive peak off-state voltage	$V_{DSM}$	300	500	700	V	
Non-repetitive peak reverse voltage	$V_{RSM}$	300	500	700	V	
Average on-state current	$I_{T(AV)}$	5.0			A	50Hz Half-cycle sinewave, Continuous current, $T_c = 96^\circ C$
RMS on-state current	$I_{T(RMS)}$	7.8			A	
Surge on-state current	$I_{TSM}$	80			A	50Hz Half-cycle sinewave, Single shot, Non-repetitive, $T_j = 125^\circ C$
Peak forward gate current	$I_{FGM}$	2.0			A	$f \geq 50Hz$ , duty $\leq 10\%$
Peak forward gate voltage	$V_{FGM}$	10			V	
Peak reverse gate voltage	$V_{RGM}$	5.0			V	$f \geq 50Hz$
Peak gate power loss	$P_{GM}$	5.0			W	$f \geq 50Hz$ , duty $\leq 10\%$
Average gate power loss	$P_{G(AV)}$	0.5			W	
Junction temperature	$T_j$	-40 to +125			$^\circ C$	
Storage temperature	$T_{stg}$	-40 to +125			$^\circ C$	

### ■ Electrical Characteristics

Parameter	Symbol	Ratings			Unit	Conditions
		min	typ	max		
Off-state current	$I_{DRM}$			2.0	mA	$T_j = 125^\circ C$ , $V_D = V_{DRM}(V_{RRM})$ , $R_{GK} = 1k\Omega$
Reverse current	$I_{RRM}$			2.0	mA	
On-state voltage	$V_{TM}$			1.4	V	$T_c = 25^\circ C$ , $I_{TM} = 10A$
Gate trigger voltage	$V_{GT}$			1.5	V	$V_D = 6V$ , $R_L = 10\Omega$ , $T_c = 25^\circ C$
Gate trigger current	$I_{GT}$		3.0	15	mA	
Gate non-trigger voltage	$V_{GD}$	0.1			V	$V_D = 1/2 \times V_{DRM}$ , $T_j = 125^\circ C$ , $R_{GK} = 1k\Omega$
Holding current	$I_H$		4.0		mA	$R_{GK} = 1k\Omega$ , $T_j = 25^\circ C$
Critical rate-of-rise of off-state voltage	$dv/dt$		50		$V/\mu S$	$V_D = 1/2 \times V_{DRM}$ , $T_j = 125^\circ C$ , $R_{GK} = 1k\Omega$ , $C_{GK} = 0.033\mu F$
Turn-off time	$t_q$		30		$\mu S$	$T_c = 25^\circ C$
Thermal resistance	$R_{th}$			3.0	$^\circ C/W$	Junction to case